

CSD13302W

Request a Quote

CSD13302W Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



CSD13302W Specifications

Manufacturer Part Number	CSD13302W
Manufacturer	Texas Instruments
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	4-UFBGA, DSBGA
Series	NexFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	12V
Current - Continuous Drain (Id) @ 25°C	1.6A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs(th) (Max) @ Id	1.3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	7.8nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	862pF @ 6V
Vgs (Max)	$\pm 10 V$
FET Feature	-
Power Dissipation (Max)	1.8W (Ta)
Rds On (Max) @ Id, Vgs	17.1 mOhm @ 1A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	4-DSBGA
Package / Case	4-UFBGA, DSBGA
	Report errors?

CSD13302W Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

CSD13302W Payment Methods WIRE PayPar PayPar Section Of MoneyGram Alice In International Internatio

If you have any question about CSD13302W, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com